AMENDMENT UNDER 37 C.F.R. § 1.114(c) Attorney Docket No.: Q90316

Appln. No.: 10/549,329

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the

application:

LISTING OF CLAIMS:

1. - 26. (canceled).

27. (previously presented): A sensor comprising a first organic substrate having a

microfluidic channel and an electronic sensing device located therein, and a second substrate

bonded to the first substrate so as to close the microfluidic channel, wherein a conducting part of

the electronic sensing device is exposed at the surface of the microfluidic channel, and said conducting part comprises poly(3.4-ethylenedioxythiophene) doped with poly(styrene sulphonic

acid).

28. (original): A sensor according to claim 27 for sensing the presence of glucose in

the microfluidic channel.

29. (canceled).

(currently amended): A method comprising:

defining in a single operation a microfluidic channel, and source and drain a pair of

electrodes of an electronic sensing device a field-effect transistor,

forming over the source and drain electrodes, an active semiconducting layer, a gate

dielectric layer and a gate electrode,

receiving a flow of liquid or gas in a portion of said microfluidic channel, and

sensing a property of said liquid or gas.

31. (previously presented): A method as claimed in claim 30 wherein the said

operation is embossing.

32. (previously presented): A method according to claim 30 wherein the microfluidic

channel is located in an organic substrate.

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 (currently amended): A method according to claim 30 wherein current flowing between the source and drain electrodes is sensitive to environmental conditions within the

channel.

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34. (previously presented): A method according to claim 33 wherein the

environmental conditions are temperature.

(previously presented): A method according to claim 33 wherein the

environmental conditions are the presence of a species to be sensed.

36. (cancelled)

37. (previously presented): A method as claimed in claim 36 wherein said field-effect

transistor is a vertical-channel field-effect transistor.

38. - 41. (canceled).

42. (currently amended): A method comprising:

forming a body comprising an electrically conductive layer;

embossing the body to define in a single operation a microfluidic channel and source and drain a pair of electrodes of a field-effect transistor, the pair of source and drain electrodes being

drain a pair or electrodes of a ricid-circet transistor, the pair or source and drain electrodes being

exposed at the surface of the channel;

forming over the source and drain electrodes, an active semiconducting layer, a dielectric

layer and a gate electrode;

receiving a flow of a liquid or gas in at least a portion of said channel; and

sensing a property of said liquid or gas.

43. (previously presented): A method as claimed in claim 42 wherein defining said

pair of electrodes comprises microcutting the electrically conductive layer.

44. (currently amended): A method as claimed in claim 42 further comprising

depositing over the body a layer of a semiconductive material to form said active semiconducting

layer.

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45. (currently amended) A method as claimed in claim 44 further comprising depositing over the layer of semiconductive material a layer of an insulating material to form said gate dielectric layer.

46. (currently amended): A method as claimed in claim 45 further comprising depositing over the layer of insulating material a layer of a conductive material to form said gate electrode.

47. (canceled).